	Application No. Applicant(s)		pplicant(s)		
Application Number	10/678,139	YA	YAMAZAKI ET AL.		
	Terminal Disclaimer Filed: 03/29/2006	-			
TERMINAL					
DISCLAIMER			☐ DISAPPROVED		
Document Code - DISQ	This patent is subject to a Terminal Disclaimer		Reasons:		
INTERNAL DOCUMENT – DO NOT MAIL					
NOTE DISCLAIMER: The term of this patent shall not extend beyond the expiration date of Pat. No. 6,331,457.					
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Docket No. 0756-2659

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re P	ATENT application of	•	.)	
SHUN	PEI YAMAZAKI et al.	•	·	
Serial :	No. 10/678,139		·)	Art Unit: 2822
Piled:	October 6, 2003	· ·)	Examiner: GUERRERO
For:	METHOD FOR FABRICAT	TING SEMICONDUC	CTOR THIN FILM)	·

TERMINAL DISCLAIMER

Commissioner for Patents P.O.Box 1450 Alexandria, VA 22313-1450

Sir:

I, Dr. Shunpei Yamazaki, having a place of business at Semiconductor Energy Laboratory Co., Ltd., 398, Hase, Atsugi-shi, Kanagawa-ken 243-0036 Japan, state that I am authorized to sign on behalf of the assignee of this invention and that the Assignment referred to below has been reviewed and certify that, to the best of my knowledge and belief, the entire right, title and interest in the above-identified application is in the name of Semiconductor Energy Laboratory Co., Ltd. by virtue of an Assignment recorded in the U.S. Patent and Trademark Office at Reel 07701, Frame 0233-0225.

Semiconductor Energy Laboratory Co., Ltd. hereby disclaims, except as provided below, the terminal part of the statutory term of any patent granted on the instant application, which would extend beyond the expiration date of the full statutory term defined in 35 U.S.C. 154 to 156 and 173, as presently shortened by any terminal disclaimer, of prior Patent No. 6,686,262, Patent No. 6,048,758, and Patent No. 6,331,457.

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Docket No. 0756-2659

Semiconductor Energy Laboratory Co., Ltd. hereby agrees that any patent so granted on the instant application shall be enforceable only for and during such period that it and prior Patent No. 6,686,262, Patent No. 6,048,758, and Patent No. 6,331,457 are commonly owned. This agreement runs with any patent granted on the instant application and is binding upon the grantee, its successors or assigns.

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I hereby declare that all statements made herein of my own knowledge are true and that all statements made on information and belief are believed to be true; and further that these statements were made with the knowledge that willful false statements and the like so made are punishable by fine or imprisonment, or both, under Section 1001 of Title 18 of the United States Code and that such willful false statements may jeopardize the validity of the application or any patent issuing thereon.

09/20/2006

Date

Name: Shuapei Yamazald

Title: President

Company Name: Semiconductor Energy Laboratory Co., Ltd.